

Isc N-Channel MOSFET Transistor

IRFP4227PBF

FEATURES

- · With TO-247 packaging
- Uninterruptible power supply
- · High speed switching
- · Hard switched and high frequency circuits
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

· Switching applications

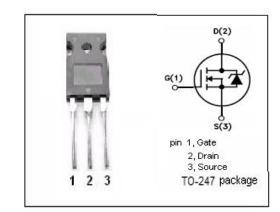


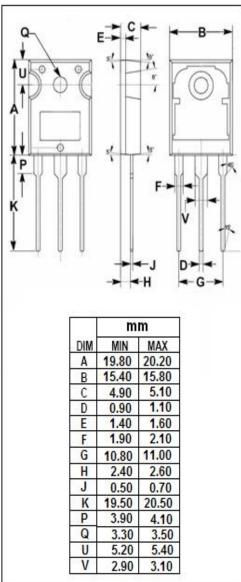
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	200	V
V _{GSS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous@ T_c =25° T_c =100° T_c	65 46	А
I_{DM}	Drain Current-Single Pulsed	260	А
P _D	Total Dissipation $@T_C=25^{\circ}C$ $T_C=100^{\circ}C$	330 190	W
T _j	Operating Junction Temperature	-40~175	${\mathbb C}$
T _{stg}	Storage Temperature	-40~175	${\mathbb C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.45	°C/W	
Rth(ch-a)	Rth(ch-a) Channel-to-ambient thermal resistance		°C/W	







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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	200			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =±20V; I _D =0.25mA	3		5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =46A		21	25	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 200V; V _{GS} = 0V@Tc=25°C Tc=125°C			20 1000	μА
V _{SDF}	Diode forward voltage	I _{SD} =46A, V _{GS} = 0 V			1.3	V

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